TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (Ultra-High-Speed U-MOSIII)

TPCA8005-H

High Efficiency DC / DC Converter Applications Notebook PC Applications

Portable Equipment Applications

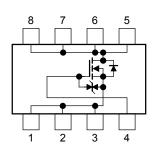
- Small footprint due to a small and thin package
- High speed switching
- Small gate charge: QSW =7.7 nC (typ.)
- Low drain-source ON-resistance: RDS (ON) = $6.8 \text{ m}\Omega$ (typ.)
- High forward transfer admittance: $|Y_{fs}| = 46 \text{ S (typ.)}$
- Low leakage current: $I_{DSS} = 10 \mu A \text{ (max) (V}_{DS} = 30 \text{ V)}$
- Enhancement mode: $V_{th} = 1.1$ to 2.3 V ($V_{DS} = 10$ V, $I_{D} = 1$ mA)

Weight: 0.069 g (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol		Unit	
Drain-source voltage		V _{DSS}	30	//	
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)		VDGR	30	N	
Gate-source voltage		V _{GSS})) ±20	V \	
Drain current	DC (Note 1)	(d)	27 〈	A	
Diaili Cullelli	Pulsed (Note 1)	(IDP)	81)\	
Drain power dissipation	on (Tc=25°C)	PD	45	W	
Drain power dissipation (t = 10 s) (Note 2a)		PD	2.8	*>> W	
Drain power dissipation (f ≠ 10 s) (Note 2b)		PD	1.6	W	
Single-pulse avalanche energy (Note 3)		E _{AS}	95	mJ	
Avalanche current		IAR	27	Α	
Repetitive avalanche energy (Tc=25°C) (Note 4)		EAR	2.7	mJ	
Channel temperature		Ich	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

Circuit Configuration



Note: For Notes 1 to 4, refer to the next page.

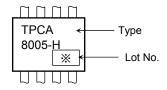
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.

Thermal Characteristics

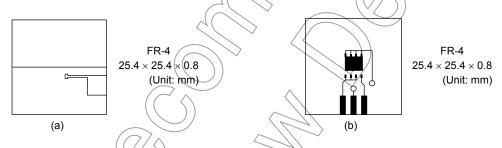
Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case (Tc=25°C)	R _{th (ch-c)}	2.78	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2a)	R _{th (ch-a)}	44.6	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R _{th (ch-a)}	78.1	°C/W

Marking (Note 5)



Note 1: The channel temperature should not exceed 450°C during use.

Note 2: (a) Device mounted on a glass-epoxy board (b) Device mounted on a glass-epoxy board (b)



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Note 3: $V_{DD} = 24 \text{ V}$, $T_{Ch} = 25^{\circ}\text{C}$ (initial), L = 0.1 mH, $R_G \neq 25^{\circ}\Omega$, $I_{AR} = 27 \text{ A}$

Note 4: Repetitive rating: pulse width limited by max. channel temperature

Note 5: * Weekly code: (Three digits)

Week of manufacture

(01) for first week of year, continuing up to 52 or 53)

Year of manufacture

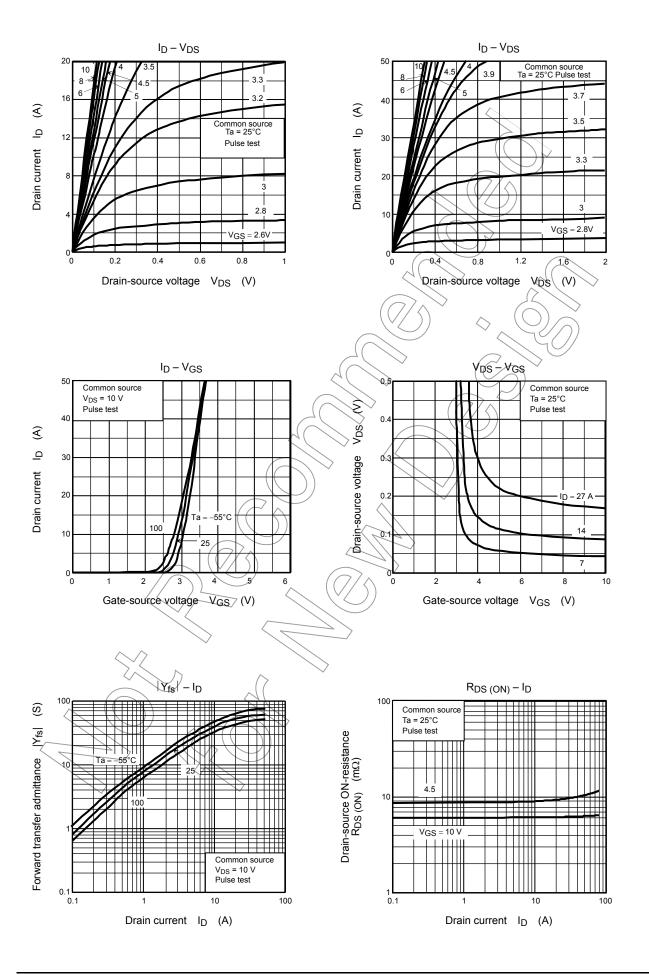
(The last digit of the calendar year)

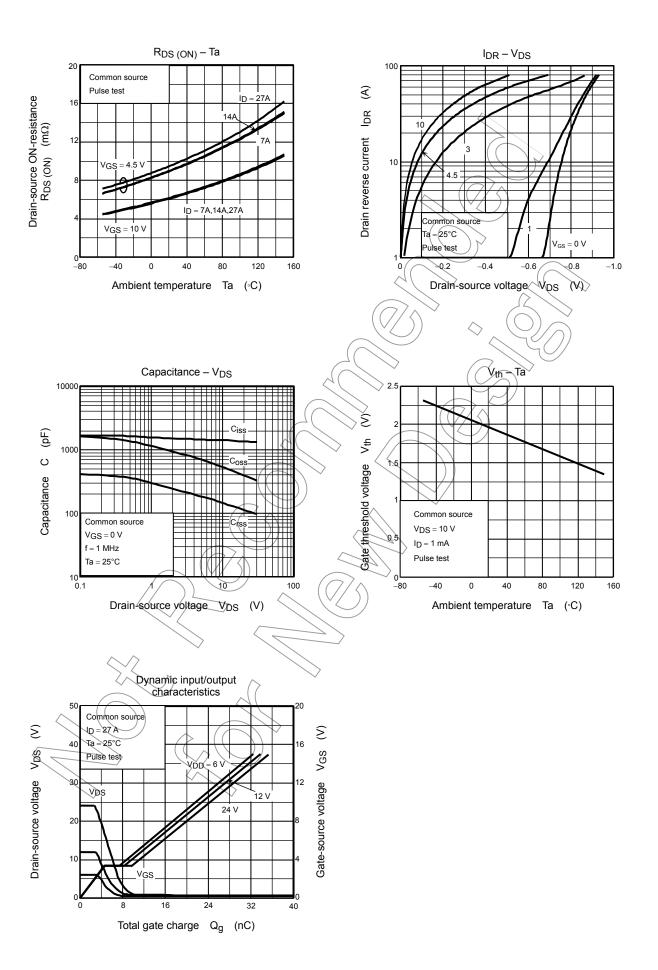
Electrical Characteristics (Ta = 25°C)

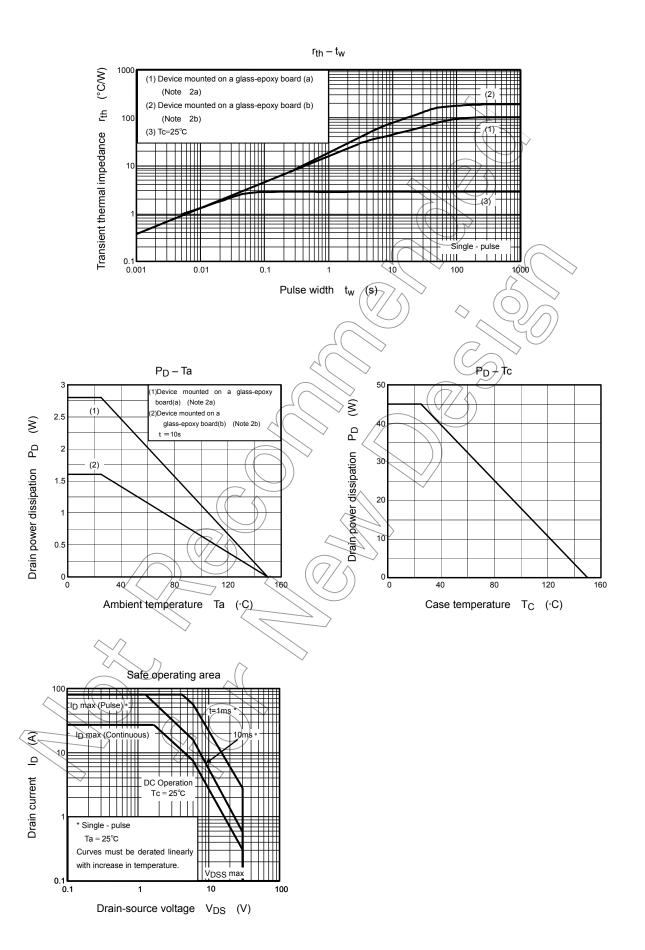
Ch	aracteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rent	I _{GSS}	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μА
Drain cutoff curre	ent	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V	_	_	10	μА
Drain-source breakdown voltage		V _{(BR)DSS}	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	30	_		V
		V _{(BR)DSX}	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	15	_		
Gate threshold vo	oltage	V _{th}	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$	7)) >	2.3	V
Drain-source ON-resistance		D	$V_{GS} = 4.5 \text{ V}, I_D = 14 \text{ A}$) /\	9.5	13	mΩ
		R _{DS} (ON)	V _{GS} = 10 V, I _D = 14 A	\rightarrow	6.8	9	
Forward transfer	admittance	Y _{fs}	V _{DS} = 10 V, I _D = 14 A	23	46		S
Input capacitance	9	C _{iss}			1395		
Reverse transfer	capacitance	C _{rss}	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	_	140	/	pF
Output capacitan	ce	Coss			525	<i>></i>	
Switching time	Rise time	t _r	10 V 17 Ip # 14A	-	3	>	
	Turn-on time	t _{on}	V _{GS} 10 V I _D ± 14A VOVOUT		9	_	ns
	Fall time	t _f	44 M		8	_	115
	Turn-off time	toff	V _{DD} ≃ 15 V Duty ≤ 1%, t _W = 10 μs) —	27	_	
Total gate charge			$V_{DD} \simeq 24 \text{ V}, V_{GS} \neq 10 \text{ V}, I_D = 27 \text{ A}$	_	24	_	
(gate-source plus	s gate-drain)	Qg	$V_{DD} \simeq 24 \text{ V}, V_{GS} = 5 \text{ V}, I_D = 27 \text{ A}$	_	13	_	
Gate-source char	rge 1	Q _{gs1}			4.7		nC
Gate-drain ("Miller") charge		Qgd	$V_{DD} \simeq 24 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 27 \text{ A}$		5.6		
Gate switch char	ge	Qsw		_	7.7	_	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristic	Symbol Test Condition	Min	Тур.	Max	Unit
Drain reverse current Pulse (Not	1) IDRP -	_	_	81	Α
Forward voltage (diode)	V_{DSF} $I_{DR} = 27 \text{ A}, V_{GS} = 0 \text{ V}$	_	_	-1.2	V







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